# 200 mA, Ultra Low Noise, High PSRR, BiCMOS RF LDO Regulator

Noise sensitive RF applications such as Power Amplifiers in satellite radios, infotainment equipment, and precision instrumentation for automotive applications require very clean power supplies.

The NCV8570 is 200 mA LDO that provides the engineer with a very stable, accurate voltage with ultra low noise and very high Power Supply Rejection Ratio (PSRR) suitable for RF applications. In order to optimize performance for battery operated portable applications, the NCV8570 employs an advanced BiCMOS process to combine the benefits of low noise and superior dynamic performance of bipolar elements with very low ground current consumption at full loads offered by CMOS.

Furthermore, in order to provide a small footprint for space-conscious applications, the NCV8570 is stable with small, low value capacitors and is available in very small DFN6 2x2.2 and TSOP-5 packages.

#### **Features**

- Output Voltage Options:
  - ◆ 1.8 V, 2.5 V, 2.75 V, 2.8 V, 3.0 V, 3.3 V
  - ◆ Contact Factory for Other Voltage Options
- Output Current Limit 200 mA
- Ultra Low Noise (typ 15 μV<sub>rms</sub>)
- Very High PSRR (typ 80 dB)
- Stable with Ceramic Output Capacitors as low as 1 µF
- Low Sleep Mode Current (max 1 μA)
- Active Discharge Circuit
- Current Limit Protection
- Thermal Shutdown Protection
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These are Pb-Free Devices

## **Typical Applications**

- Satellite and HD Radio
- Noise Sensitive Applications (Video, Audio)
- Analog Power Supplies
- Portable/Built-in DVD Entertainment Systems
- GPS

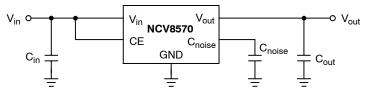


Figure 1. Typical Application Schematic



## ON Semiconductor®

http://onsemi.com

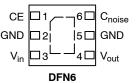


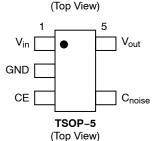




TSOP-5 SN SUFFIX CASE 483

#### **PIN ASSIGNMENTS**





#### **MARKING DIAGRAMS**



XX = Specific Device Code

M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)



XXX = Specific Device Code

A = Assembly Location

Y = Year

W = Work Week

= Pb-Free Package

(Note: Microdot may be in either location)

#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 9 of this data sheet.

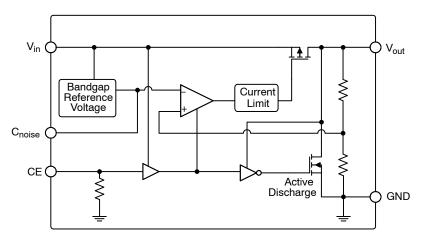


Figure 2. Simplified Block Diagram

## **PIN FUNCTION DESCRIPTION**

Pin No. DFN6	TSOP-5	Pin Name	Description
1	3	CE	Chip Enable: This pin allows on/off control of the regulator. To disable the device, connect to GND. If this function is not in use, connect to $V_{in}$ . Internal 5 M $\Omega$ Pull Down resistor is connected between CE and GND.
2, 5, EPAD	2	GND	Power Supply Ground (Pins are fused for the DFN package)
3	1	V <sub>in</sub>	Power Supply Input Voltage
4	5	V <sub>out</sub>	Regulated Output Voltage
6	4	C <sub>noise</sub>	Noise reduction pin. (Connect 100 nF or 10 nF capacitor to GND)

## **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Input Voltage (Note 1)	V <sub>in</sub>	-0.3 V to 6 V	V
Chip Enable Voltage	V <sub>CE</sub>	-0.3 V to V <sub>in</sub> +0.3 V	V
Noise Reduction Voltage	V <sub>Cnoise</sub>	-0.3 V to V <sub>in</sub> +0.3 V	V
Output Voltage	V <sub>out</sub>	-0.3 V to V <sub>in</sub> +0.3 V	V
Maximum Junction Temperature (Note 1)	T <sub>J(max)</sub>	150	°C
Storage Temperature Range	T <sub>STG</sub>	-55 to 150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

NOTE: This device series contains ESD protection and exceeds the following tests:

Human Body Model 2000 V per MIL-STD-883, Method 3015

Machine Model Method 200 V

This device series meets or exceeds AEC Q100 standard.

## THERMAL CHARACTERISTICS

Rating	Symbol	Value	Unit
Package Thermal Resistance, DFN6: (Note 1) Junction-to-Lead (pin 2) Junction-to-Ambient	$R_{ heta JA}$	37 120	°C/W
Package Thermal Resistance, TSOP-5: (Note 1) Junction-to-Lead (pin 5) Junction-to-Ambient	$R_{ heta JA}$	109 220	°C/W

1. Refer to ELECTRICAL CHARACTERISTICS and APPLICATION INFORMATION for Safe Operating Area

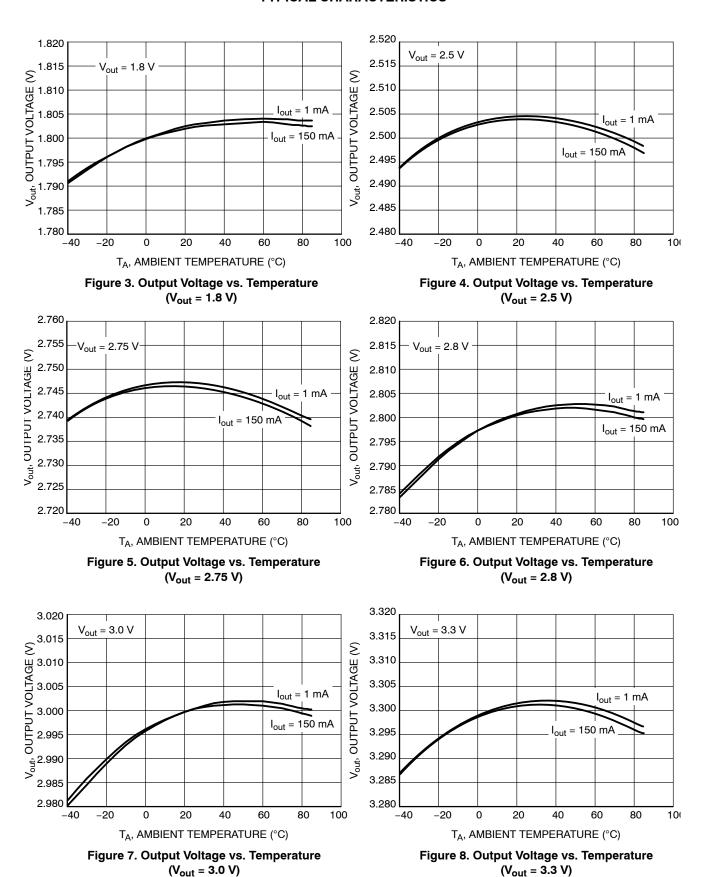
## **ELECTRICAL CHARACTERISTICS**

 $(V_{in} = V_{out} + 0.5 \text{ V}, V_{CE} = 1.2 \text{ V}, C_{in} = 0.1 \text{ } \mu\text{F}, C_{out} = 1 \text{ } \mu\text{F}, C_{noise} = 10 \text{ nF}, T_{A} = -40^{\circ}\text{C} \text{ to } 85^{\circ}\text{C}, unless \text{ otherwise specified (Note 2))}$ 

Characteristic		Test Conditions	Symbol	Min	Тур	Max	Unit
REGULATOR OUTPUT			•		-	•	•
Input Voltage			V <sub>in</sub>	2.5	_	5.5	V
Output Voltage (Note 3)	1.8 V 2.5 V 2.75 V 2.8 V 3.0 V 3.3 V	$V_{in} = (V_{out} + 0.5 \text{ V}) \text{ to } 5.5 \text{ V}$ $I_{out} = 1 \text{ mA}$	V <sub>out</sub>	1.764 2.450 2.695 2.744 2.940 3.234 (-2%)	- - - - -	1.836 2.550 2.805 2.856 3.060 3.366 (+2%)	V
Output Voltage (Note 3)	1.8 V 2.5 V 2.75 V 2.8 V 3.0 V 3.3 V	V <sub>in</sub> = (V <sub>out</sub> +0.5 V) to 5.5 V I <sub>out</sub> = 1 mA to 200 mA	V <sub>out</sub>	1.746 2.425 2.6675 2.716 2.910 3.201 (-3%)	- - - - -	1.854 2.575 2.8325 2.884 3.090 3.399 (+3%)	V
Power Supply Ripple Rejection		$ \begin{aligned} &V_{in} = V_{out} + 1.0 \text{ V} + 0.5 \text{ V}_{p-p} \\ &I_{out} = 1 \text{ mA to } 150 \text{ mA} \end{aligned}  \begin{aligned} &f = 120 \text{ Hz} \\ &C_{noise} = 100 \text{nF} \end{aligned}  \begin{aligned} &f = 1 \text{ kHz} \\ &f = 10 \text{ kHz} \end{aligned}$	PSRR	- - -	80 80 65	- - -	dB
Line Regulation		$V_{in} = (V_{out} + 0.5 \text{ V}) \text{ to } 5.5 \text{ V}, I_{out} = 1 \text{ mA}$	Reg <sub>line</sub>	-0.2	_	0.2	%/V
Load Regulation		I <sub>out</sub> = 1 mA to 200 mA	Reg <sub>load</sub>	-	12	25	mV
Output Noise Voltage		$ \begin{aligned} & \text{f} = \text{10 Hz to 100 kHz} \\ & \text{I}_{\text{out}} = \text{1 mA to 150 mA} & \text{C}_{\text{noise}} = \text{100 nF} \\ & \text{C}_{\text{noise}} = \text{10 nF} \end{aligned} $	V <sub>n</sub>	- -	15 20	- -	μV <sub>rms</sub>
Output Current Limit		V <sub>out</sub> = V <sub>out(nom)</sub> - 0.1 V	I <sub>LIM</sub>	200	310	470	mA
Output Short Circuit Current		V <sub>out</sub> = 0 V	I <sub>SC</sub>	210	320	490	mA
Dropout Voltage (Note 4, 5)	2.5 V 2.75 V 2.8 V 3.0 V 3.3 V	I <sub>out</sub> = 150 mA	V <sub>DO</sub>	- - - -	105 105 105 100 100	155 155 155 150 150	mV
Dropout Voltage (Note 6)	2.5 V 2.75 V 2.8 V 3.0 V 3.3 V	I <sub>out</sub> = 200 mA	V <sub>DO</sub>	- - - -	170 150 150 140 130	215 205 205 200 200	mV
GENERAL			•	•		•	•
Ground Current		$I_{out} = 1 \text{ mA}$ $I_{out} = 200 \text{ mA}$	I <sub>GND</sub>	- -	70 110	90 220	μΑ
Disable Current		V <sub>CE</sub> = 0 V	I <sub>DIS</sub>	-	0.1	1	μΑ
Thermal Shutdown Threshold (Note 4)			T <sub>SD</sub>	-	150	-	°C
Thermal Shutdown Hysteresis (Note 4)			T <sub>SH</sub>	-	20	-	°C
CHIP ENABLE			<u> </u>	<u> </u>			
Input Threshold	Low High		V <sub>th(CE)</sub>	- 1.2	_ _	0.4 -	V
Internal Pull-Down Resistance	(Note 7)		R <sub>PD(CE)</sub>	2.5	5	10	$M\Omega$
TIMING							
Turn-on Time		$\label{eq:continuous} \begin{array}{c} I_{out} = 150 \text{ mA} & C_{noise} = 10 \text{ nF} \\ C_{noise} = 100 \text{ nF} \end{array}$	t <sub>on</sub>	- -	0.4 4	- -	ms
Turn-off Time		$C_{noise} = 10 \text{ nF}/100 \text{ nF}$ $I_{out} = 1 \text{ mA}$ $I_{out} = 10 \text{ mA}$	t <sub>off</sub>	- -	800 200	- -	μs

Performance guaranteed over the indicated operating temperature range by design and/or characterization, production tested at T<sub>J</sub> = T<sub>A</sub> = 25°C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.
 Contact factory for other voltage options.
 Guaranteed by design and characterization.
 Characterized when output voltage falls 100 mV below the regulated voltage at V<sub>in</sub> = V<sub>out</sub> + 1 V if V<sub>out</sub> < 2.5 V, then V<sub>DO</sub> = V<sub>in</sub> - V<sub>out</sub> at V<sub>in</sub> = 2.5 V.
 Measured when output voltage falls 100 mV below the regulated voltage at V<sub>in</sub> = V<sub>out</sub> + 0.5 V if V<sub>out</sub> < 2.5 V, then V<sub>DO</sub> = V<sub>in</sub> - V<sub>out</sub> at V<sub>in</sub> = 2.5 V.
 Expected to disable device when CE pin is floating.

## **TYPICAL CHARACTERISTICS**



## **TYPICAL CHARACTERISTICS**

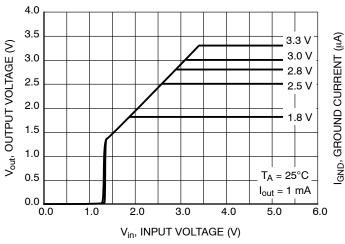


Figure 9. Output Voltage vs. Input Voltage

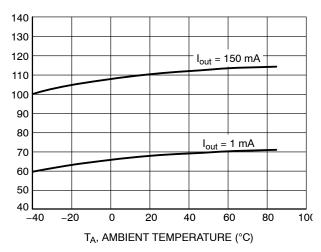


Figure 10. Ground Current vs. Temperature

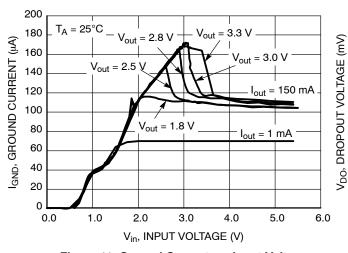


Figure 11. Ground Current vs. Input Voltage

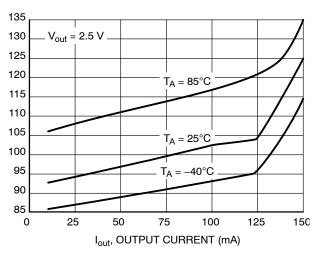


Figure 12. Dropout Voltage vs. Output Current

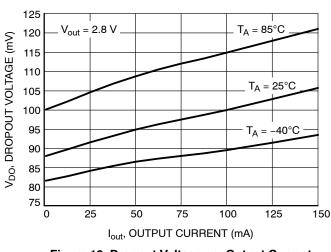


Figure 13. Dropout Voltage vs. Output Current

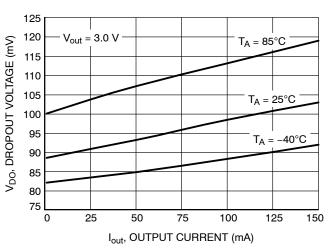


Figure 14. Dropout Voltage vs. Output Current

## **TYPICAL CHARACTERISTICS**

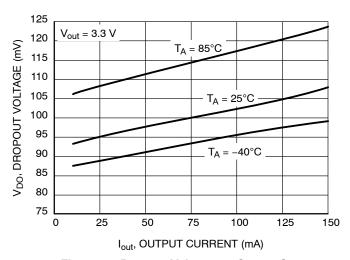
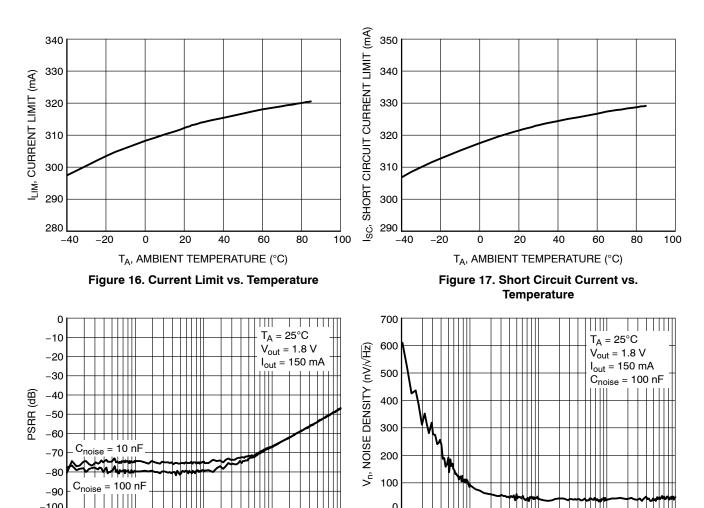


Figure 15. Dropout Voltage vs. Output Current



f, FREQUENCY (Hz) Figure 18. PSRR vs. Frequency

1,000

10,000

10

100

FREQUENCY (Hz)

Figure 19. Noise Density vs. Frequency

1,000

10,000

100,000

100,000

10

100

## **TYPICAL CHARACTERISTICS**

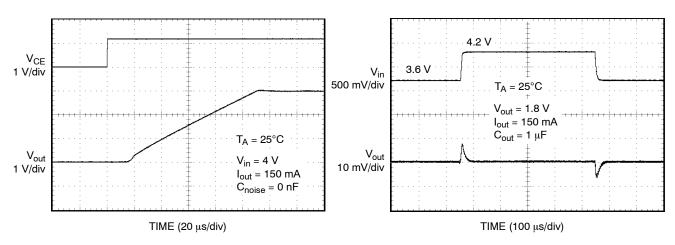


Figure 20. Enable Voltage and Output Voltage vs. Time (Start-Up)

Figure 21. Line Transient

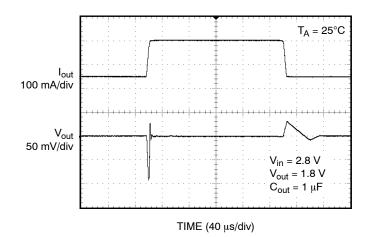


Figure 22. Load Transient

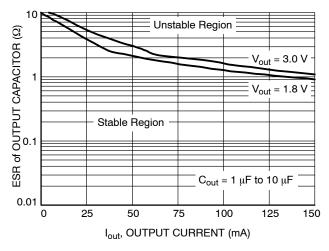


Figure 23. Output Capacitor ESR vs. Output Current

#### APPLICATION INFORMATION

#### General

The NCV8570 is a 200 mA (current limited) linear regulator with a logic input for on/off control for the high speed turn-off output voltage.

Access to the major contributor of noise within the integrated circuit is provided as the focus for noise reduction within the linear regulator system.

## Power Up/Down

During power up, the NCV8570 maintains a high impedance output  $(V_{out})$  until sufficient voltage is present on  $V_{in}$  to power the internal bandgap reference voltage. When sufficient voltage is supplied (approx 1.2 V),  $V_{out}$  will start to turn on (assume CE shorted to  $V_{in}$ ), linearly increasing until the output regulation voltage has been reached.

Active discharge circuitry has been implemented to insure a fast turn off time. Then CE goes low, the active discharge transistor turns on creating a fast discharge of the output voltage. Power to drive this circuitry is drawn from the output node. This is to maintain the lowest quiescent current when in the sleep mode ( $V_{CE} = 0.4 \text{ V}$ ). This circuitry subsequently turns off when the output voltage discharges.

## CE (chip enable)

The enable function is controller by the logic pin CE. The voltage threshold of this pin is set between 0.4 V and 1.2 V. A voltage lower than 0.4 V guarantees the device is off. A voltage higher than 1.2 V guarantees the device is on. The NCV8570 enters a sleep mode when in the off state drawing less than 1  $\mu A$  of quiescent current.

The device can be used as a simple regulator without use of the chip enable feature by tying the CE pin to the  $V_{in}$  pin.

#### **Current Limit**

Output Current is internally limited within the IC to a minimum of 200 mA. The design is set to a higher value to allow for variation in processing and the temperature coefficient of the parameter. The NCV8570 will source this amount of current measured with a voltage 100 mV lower than the typical operating output voltage.

The specification for short circuit current limit (@ $V_{out} = 0~V$ ) is specified at 320 mA (typ). There is no additional circuitry to lower the current limit at low output voltages. This number is provided for informational purposes only.

#### **Output Capacitor**

The NCV8570 has been designed to work with low ESR ceramic capacitors. There is no ESR lower limit for stability for the recommended 1  $\mu$ F output capacitor. Stable region for Output capacitor ESR vs Output Current is shown in Figure 23.

Typical characteristics were measured with Murata ceramic capacitors. GRM219R71E105K (1  $\mu$ F, 25 V, X7R, 0805) and GRM21BR71A106K (10  $\mu$ F, 10 V, X7R, 0805).

## **Output Noise**

The main contributor for noise present on the output pin  $V_{out}$  is the reference voltage node. This is because any noise which is generated at this node will be subsequently amplified through the error amplifier and the PMOS pass device. Access to the reference voltage node is supplied directly through the  $C_{noise}$  pin. Noise can be reduced from a typical value of  $20~\mu V_{rms}$  by using 10~nF to  $15~\mu V_{rms}$  by using a 100~nF from the  $C_{noise}$  pin to ground.

A bypass capacitor is recommended for good noise performance and better load transient response.

#### **Thermal Shutdown**

When the die temperature exceeds the Thermal Shutdown threshold, a Thermal Shutdown (TSD) event is detected and the output (V<sub>out</sub>) is turned off. There is no effect from the active discharge circuitry. The IC will remain in this state until the die temperature moves below the shutdown threshold (150°C typical) minus the hysteresis factor (20°C typical).

This feature provides protection from a catastrophic device failure due to accidental overheating. It is not intended to be used as a substitute for proper heat sinking. The maximum device power dissipation can be calculated by:

$$P_{D} = \frac{T_{J} - T_{A}}{R_{\theta, IA}}$$

Thermal resistance value versus copper area and package is shown in Figure 24.

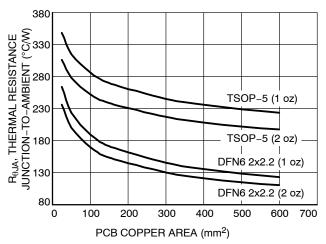


Figure 24.  $R_{\theta JA}$  vs. PCB Copper Area

(TSOP-5 for comparison only)

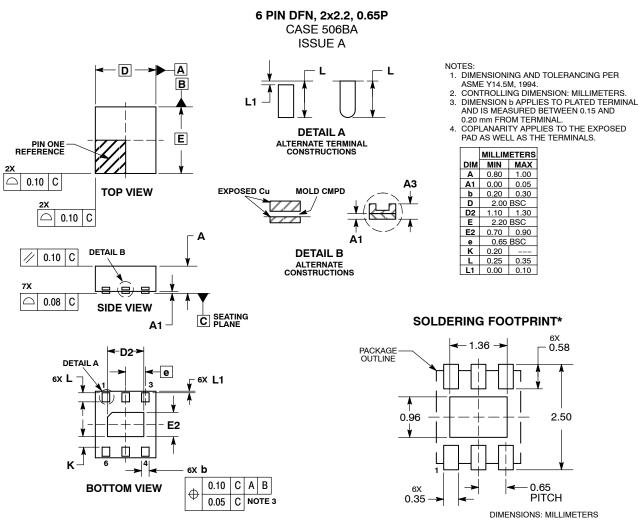
## **ORDERING INFORMATION**

Device*	Nominal Output Voltage	Marking	Package	Shipping†		
NCV8570MN180R2G	1.8 V	MT				
NCV8570MN250R2G	2.5 V	MU		0000 /T 00 P 1		
NCV8570MN275R2G	2.75 V	MV	DFN6			
NCV8570MN280R2G	2.8 V	MW	2x2.2 (Pb-Free)	3000 / Tape & Reel		
NCV8570MN300R2G	3.0 V	MX				
NCV8570MN330R2G	3.3 V	MY				
NCV8570SN18T1G	1.8 V	ACV		2000 (7 0 D . 1		
NCV8570SN25T1G	2.5 V	ACW				
NCV8570SN275T1G	2.75 V	ACX	TSOP-5			
NCV8570SN28T1G	2.8 V	ACY	(Pb-Free)	3000 / Tape & Reel		
NCV8570SN30T1G	3.0 V	ACZ				
NCV8570SN33T1G	3.3 V	AC2				

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
\*NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP

Capable

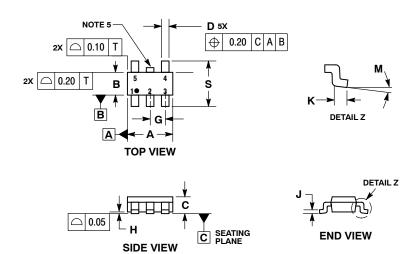
#### PACKAGE DIMENSIONS



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### PACKAGE DIMENSIONS

## TSOP-5 CASE 483-02 ISSUE K

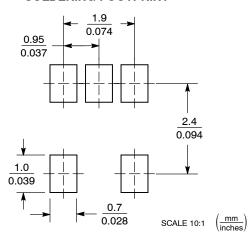


#### NOTES

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
  CONTROLLING DIMENSION: MILLIMETERS.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE
- MINIMUM THICKNESS OF BASE MATERIAL.
  DIMENSIONS A AND B DO NOT INCLUDE MOLD DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE. DIMENSION A. OPTIONAL CONSTRUCTION: AN ADDITIONAL TRIMMED LEAD IS ALLOWED IN THIS LOCATION.
- TRIMMED LEAD NOT TO EXTEND MORE THAN 0.2 FROM BODY.

	MILLIMETERS			
DIM	MIN	MAX		
Α	3.00	3.00 BSC		
В	1.50 BSC			
С	0.90	1.10		
D	0.25	0.50		
G	0.95 BSC			
Н	0.01	0.10		
J	0.10	0.26		
K	0.20	0.60		
М	0 °	10°		
S	2 50	3.00		

#### **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

The products described herein (NCV8570), may be covered by one or more U.S. patents.

ON Semiconductor and 📖 are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of SCILLC's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking, pdf. SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

## **PUBLICATION ORDERING INFORMATION**

#### LITERATURE FULFILLMENT: Literature Distribution Center for ON Semiconductor

P.O. Box 5163, Denver, Colorado 80217 USA **Phone**: 303–675–2175 or 800–344–3860 Toll Free USA/Canada **Fax**: 303–675–2176 or 800–344–3867 Toll Free USA/Canada

Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free USA/Canada

Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81-3-5817-1050

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative